Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.412 inches and 0.450 inches
Overall Diameter:
Between 0.667 inches and 0.685 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-5
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Threaded stud
Overall Width Across Flats:
Between 0.667 inches and 0.685 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
60.00 amperes forward current, average
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0